

**TO:** The Faculty of the College of Engineering

**FROM:** School of Electrical and Computer Engineering of the College of Engineering

**RE:** New Graduate Course, ECE 60614 Reliability Physics of Nanoelectronic Transistors

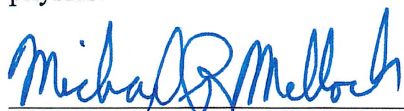
The faculty of the School of Electrical and Computer Engineering has approved the following new course. This action is now submitted to the Engineering Faculty with a recommendation for approval.

**ECE 60614 Reliability Physics of Nanoelectronic Transistors**

Sem. 2, Lecture 3, Cr. 3.  
Prerequisite: ECE 60600

**Description:** This course will focus on the physics of reliability of small semiconductor devices. In traditional courses on device physics, the students learn how to compute current through a device in response to applied voltage. However, as transistors are turned on and off trillions of times during the years of operation, gradually defects accumulate within the device so that at some point the transistor does not work anymore. The course will explore the physics and mathematics regarding how and when things break—a topic of great interest to semiconductor device engineers.

**Reason:** Modern integrated circuits are made possible by billions of impossibly small transistors. Every microelectronic and nanotechnology program teaches its students the physics of transistor performance (e.g. ECE606, ECE612). Equally important (and no less astonishing) is the fact that these nanoscale transistors survive trillions of switching operation under an electric field a thousand times larger than the high voltage power-lines that crisscross the country. At universities, reliability physics of transistors is taught as an afterthought -- and yet, industry would ask their employees to learn this fundamentally important topic from the very first day of their job. This course fills the essential gap, and does so with a deep appreciation of the physics involved and the practical aspect of transistor design. This unique course will broaden/deepen the understanding of transistor physics of every student, and make our students uniquely qualified. This course requires a reasonably good understanding of semiconductor device physics.



*Michael R. Melloch, Associate Head*  
School of Electrical and Computer Engineering

Approved for the faculty of the Schools  
of Engineering by the Engineering  
Curriculum Committee

ECC Minutes 8 Date 11/20/15  
Chairman ECC [Signature]

**PURDUE UNIVERSITY**  
**REQUEST FOR ADDITION, EXPIRATION,**  
**OR REVISION OF A GRADUATE COURSE**  
**(50000-60000 LEVEL)**

DEPARTMENT Electrical and Computer Engineering EFFECTIVE SESSION Spring 2017

**INSTRUCTIONS:** Please check the items below which describe the purpose of this request.

<input checked="" type="checkbox"/> 1. New course with supporting documents (complete proposal form)	<input type="checkbox"/> 7. Change in course attributes
<input type="checkbox"/> 2. Add existing course offered at another campus	<input type="checkbox"/> 8. Change in instructional hours
<input type="checkbox"/> 3. Expiration of a course	<input type="checkbox"/> 9. Change in course description
<input type="checkbox"/> 4. Change in course number	<input type="checkbox"/> 10. Change in course requisites
<input type="checkbox"/> 5. Change in course title	<input type="checkbox"/> 11. Change in semesters offered
<input type="checkbox"/> 6. Change in course credit/type	<input type="checkbox"/> 12. Transfer from one department to another

<b>PROPOSED:</b> Subject Abbreviation <u>ECE</u> Course Number <u>60614</u> Long Title <u>Reliability Physics of Nanoelectronic Transistors</u> Short Title <u>Reliab Phys Nanoelectr Trans</u> <small>Abbreviated title will be entered by the Office of the Registrar if omitted. (30 CHARACTERS ONLY)</small>	<b>EXISTING:</b> Subject Abbreviation _____ Course Number _____	<b>TERMS OFFERED</b> Check All That Apply: <input type="checkbox"/> Fall <input checked="" type="checkbox"/> Spring <input type="checkbox"/> Summer <b>CAMPUS(ES) INVOLVED</b> <input type="checkbox"/> Calumet <input type="checkbox"/> N. Central <input type="checkbox"/> Cont Ed <input type="checkbox"/> Tech Statewide <input type="checkbox"/> Ft. Wayne <input checked="" type="checkbox"/> W. Lafayette <input type="checkbox"/> Indianapolis
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<b>CREDIT TYPE</b> 1. Fixed Credit: Cr. Hrs. <u>3</u> 2. Variable Credit Range: Minimum Cr. Hrs _____ (Check One) To <input type="checkbox"/> Or <input type="checkbox"/> Maximum Cr. Hrs _____ 3. Equivalent Credit: Yes <input type="checkbox"/> No <input checked="" type="checkbox"/> 4. Thesis Credit: Yes <input type="checkbox"/> No <input checked="" type="checkbox"/>	<b>COURSE ATTRIBUTES:</b> Check All That Apply 1. Pass/Not Pass Only <input type="checkbox"/> 2. Satisfactory/Unsatisfactory Only <input type="checkbox"/> 3. Repeatable <input type="checkbox"/> Maximum Repeatable Credit: _____ 4. Credit by Examination <input type="checkbox"/> 5. Fees <input type="checkbox"/> Coop <input type="checkbox"/> Lab <input type="checkbox"/> Rate Request <input type="checkbox"/> Include comment to explain fee _____ 6. Registration Approval Type Department <input type="checkbox"/> Instructor <input type="checkbox"/> 7. Variable Title <input type="checkbox"/> 8. Honors <input type="checkbox"/> 9. Full Time Privilege <input type="checkbox"/> 10. Off Campus Experience <input type="checkbox"/>
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Schedule Type	Minutes Per Mtg	Meetings Per Week	Weeks Offered	% of Credit Allocated	Cross-Listed Courses
Lecture	50	3	16	100	
Recitation					
Presentation					
Laboratory					
Lab Prep					
Studio					
Distance					
Clinic					
Experiential					
Research					
Ind. Study					
Pract/Observ					

**COURSE DESCRIPTION (INCLUDE REQUISITES/RESTRICTIONS):**  
This course will focus on the physics of reliability of small semiconductor devices. In traditional courses on device physics, the students learn how to compute current through a device in response to applied voltage. However, as transistors are turned on and off trillions of times during the years of operation, gradually defects accumulate within the device so that at some point the transistor does not work anymore. The course will explore the physics and mathematics

**\*COURSE LEARNING OUTCOMES:**  
i. The students will have deep understanding regarding a topic of broad interest to academic community and to the industry.  
ii. The class quizzes, homework, and exams will involve critical thinking related to broad range of topics involving various aspects of reliability physics.

Calumet Department Head _____ Date _____	Calumet School Dean _____ Date _____	Calumet Director of Graduate Studies _____ Date _____
Fort Wayne Department Head _____ Date _____	Fort Wayne School Dean _____ Date _____	Fort Wayne Director of Graduate Studies _____ Date _____
Indianapolis Department Head _____ Date _____	Indianapolis School Dean _____ Date _____	IUPUI Associate Dean for Graduate Education _____ Date _____
North Central Department Head _____ Date _____	North Central School Dean _____ Date _____	North Central Director of Graduate Studies _____ Date _____
West Lafayette Department Head <u>Michael B. Miller</u> _____ Date <u>10/8/15</u>	West Lafayette College/School Dean <u>Michael J. Namin</u> _____ Date <u>11/20/15</u>	Date Approved by Graduate Council _____ Date _____
Graduate Area Committee Convener _____ Date _____	Graduate Dean _____ Date _____	Graduate Council Secretary _____ Date _____
		West Lafayette Registrar _____ Date _____

**Supporting Document to the Form 40G  
for a New Graduate Course**

**To:** Purdue University Graduate Council

**From:** Faculty Member: Ashraf Alam

Department: Electrical and Computer Engineering

Campus: West Lafayette

**Date:**

**Subject:** Proposal for New Graduate Course

**Contact for information if questions arise:** Name: Matt Golden  
Phone: 494-3374  
Email: goldenm@purdue.edu  
Address: EE Building, Room 135

**Course Subject Abbreviation and Number:** ECE 60614

**Course Title:** Reliability Physics of Nanoelectronic Transistors

**Course Description:**

This course will focus on the physics of reliability of small semiconductor devices. In traditional courses on device physics, the students learn how to compute current through a device in response to applied voltage. However, as transistors are turned on and off trillions of times during the years of operation, gradually defects accumulate within the device so that at some point the transistor does not work anymore. The course will explore the physics and mathematics regarding how and when things break—a topic of great interest to semiconductor device engineers.

**Semesters Offered:**

For the benefit of graduate student plan of study development, how frequently will this prototype be offered? Which semesters?  
Spring odd years.

**A. Justification for the Course:**

Provide a complete and detailed explanation of the need for the course (e. g., in the preparation of students, in providing new knowledge/training in one or more topics, in meeting degree requirements, etc.), how the course contributes to existing majors and/or concentrations, and how the course relates to other graduate courses offered by the department, other departments, or interdisciplinary programs.

Justify the level of the proposed graduate course (500- or 600-level) including statements on, but not limited to: (1) the target audience, including the anticipated number of undergraduate and graduate students who will enroll in the course; and (2) the rigor of the course.

- Modern integrated circuits are made possible by billions of impossibly small transistors. Every microelectronic and nanotechnology program teaches its students the physics of transistor performance (e.g. ECE606, ECE612). Equally important (and no less astonishing) is the fact that these nanoscale transistors survive trillions of switching operation under an electric field a thousand times larger than the high voltage power-lines that crisscross the country. At universities, reliability physics of transistors is taught as an afterthought -- and yet, industry would ask their employees to learn this fundamentally important topic from the very first day of their job. This course fills the essential gap, and does so with a deep appreciation of the physics involved and the practical aspect of transistor design. This unique course will broaden/deepen the understanding of transistor physics of every students, and make our students uniquely qualified. This course requires a reasonably good understanding of semiconductor device physics.

Use the following criteria:

*Graduate Council policy requires that courses at the 50000 level in the Purdue system should be taught at the graduate level and meet four criteria: a) the use of primary literature in conjunction with advanced secondary sources (i.e., advanced textbooks); b) assessments that demonstrate synthesis of concepts and ideas by students; c) demonstrations that topics are current, and; d) components that emphasize research approaches/methods or discovery efforts in the course content area (reading the research, critiquing articles, proposing research, performing research). Such courses should be taught so that undergraduate students are expected to rise to the level of graduate work and be assessed in the same manner as the graduate students.*

- Anticipated enrollment
  - Undergraduate 0
  - Graduate 20-25

## **B. Learning Outcomes and Method of Evaluation or Assessment:**

ECE Graduate Learning Outcomes:

- a. Knowledge and Scholarship (thesis/non-thesis)
  - b. Communication (thesis/non-thesis)
  - c. Critical Thinking (thesis/non-thesis)
  - d. Ethical and Responsible Research (thesis) or Professional and Ethical Responsibility (non-thesis)
- List Learning Objectives for this course and map each Learning Objective to one or more of the ECE Learning Outcomes (a-d, listed above):
    - i. The students will have deep understanding regarding a topic of broad interest to academic community and to the industry. (a)
    - ii. The class quizzes, homework, and exams will involve critical thinking related to broad range of topics involving various aspects of reliability physics. (c)
  - Methods of Instruction
    - Lecture
  - Will/can this course be offered via Distance Learning?
    - No.
  - Grading Criteria

Grading criteria (select from checklist); include a statement describing the criteria that will be used to assess students and how the final grade will be determined. Add and delete rows as needed.

- exams and/or quizzes
  - papers and/or projects
  - homework
- ▶ Describe the criteria that will be used to assess students and how the final grade will be determined:  
A combination of scores from exams, quizzes, homework, and projects.

**C. Prerequisite(s):**

List prerequisites and/or experiences/background required. If no prerequisites are indicated, provide an explanation for their absence. Add bullets as needed.

- EE606 required; EE612, EE658 are good to have, but not essential

**D. Course Instructor(s):**

Provide the name, rank, and department/program affiliation of the instructor(s). Is the instructor currently a member of the Graduate Faculty? (If the answer is no, indicate when it is expected that a request will be submitted.) Add rows as needed.

Name	Rank	Dept.	Graduate Faculty or expected date
Ashraf Alam	Professor	ECEN	Yes

**E. Course Outline:**

Provide an outline of topics to be covered and indicate the relative amount of time or emphasis devoted to each topic. If laboratory or field experiences are used to supplement a lecture course, explain the value of the experience(s) to enhance the quality of the course and student learning. For special topics courses, include a sample outline of a course that would be offered under the proposed course. **(This information must be listed and may be copied from syllabus).**

Lectures	Principal Topics
3	Reliability Physics -- Broad Introduction
3	Spatial Randomness and Nature of Defects
6	Interface Reliability of Semiconductor Devices: NBTI Degradation
4	Interface Reliability of Semiconductor Devices: Hot Carrier Degradation
7	Time-Dependent Dielectric Breakdown
2	Breakdown in Thick Dielectrics
5	Radiation Damage in Semiconductor Devices
4	Statistics of Reliability
4	Theory and Practice of Defect Characterization
2	Concluding Remarks

**F. Reading List (including course text):**

A primary reading list or bibliography should be limited to material the students will be required to read in order to successfully complete the course. It should not be a compilation of general reference material.

A secondary reading list or bibliography should include material students may use as background information.

- Primary Reading List
  - None
- Secondary Reading List
  - Lecture Notes from 2013  
(<https://nanohub.org/resources/16560>)
  - Lecture Notes from 2013  
(<https://sites.google.com/site/teachingreliabilityclassnotes/2010-word-documents>)
  - Fundamentals of Modern VLSI Devices Yuan Taur and Tak H. Ning, Cambridge University Press, 1998 ISBN: 0 521 55056 4 (hardback) or 0 521 55959 6 (paperback)
  - Advanced Semiconductor Fundamentals, 2nd Edition R.F. Pierret, Prentice Hall, ISBN 0-13-061792-X
  - Semiconductor Material and Device Characterization, D. K. Schroeder, John Wiley and Sons, ISBN: 0-471-73906-5

### **G. Library Resources**

Describe any library resources that are currently available or the resources needed to support this proposed course.

- None.

### **H. Course Syllabus**

(While not a necessary component of this supporting document, an example of a course syllabus is available, for information, by clicking on the link below, which goes to the *Graduate School's Policies and Procedures Manual for Administering Graduate Student Program*.

See Appendix K.

**[http://www.purdue.edu/gradschool/faculty/documents/Graduate School Policies and Procedures Manual.pdf](http://www.purdue.edu/gradschool/faculty/documents/Graduate_School_Policies_and_Procedures_Manual.pdf)**